

## SAM<sup>TM</sup> Data Sheet SAM-1040-4-800fs-x, $\lambda$ = 1040 nm

Laser wavelength  $\lambda = 1040 \text{ nm}$ 

High reflection band  $\lambda = 1010 ... 1060 \text{ nm}$ 

Absorbance  $A_0 = 4 \%$  Modulation depth  $\Delta R = 2.6 \%$  Non-saturable loss  $A_{ns} = 1.4 \%$ 

Saturation fluence  $\Phi_{\text{sat}} = 120 \, \mu \text{J/cm}^2$ 

Relaxation time constant  $\tau = 800 \text{ fs}$ 

Damage threshold  $\Phi = 3 \text{ mJ/cm}^2$ 

Chip area 4.0 mm x 4.0 mm; other dimensions on request

Chip thickness 450 µm

Protection the SAM is protected with a dielectric front layer

Mounting option **x** denotes the type of mounting as follows:

x = 0
x = 12.7 g
x = 25.4 g
x = 12.7 s
x = 12.7 s
x = 12.7 s
x = 12.7 s
x = 25.4 s
x = 25.4 s
x = 25.0 w
x

## Low intensity spectral reflectance and dispersion

